

Features

- AEC-Q101 Qualified
- Excellent Package For Heat Dissipation
- High Density Cell Design For Low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Halogen Free "Green" Device^(Note1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant^(Note2) ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

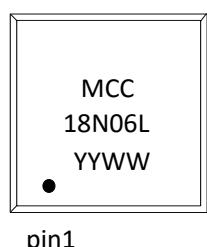
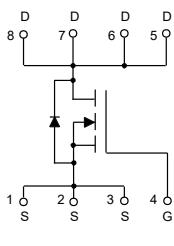
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 60°C/W Junction to Ambient^(Note2)
- Thermal Resistance: 2.1°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current $T_J=25^\circ\text{C}$	I_D	30	A
$T_J=100^\circ\text{C}$	I_D	19	
Pulsed Drain Current (Note3)	I_{DM}	120	A
Total Power Dissipation ^(Note4)	P_D	59	W
Single Pulse Avalanche Energy (Note5)	E_{AS}	55	mJ

Note:

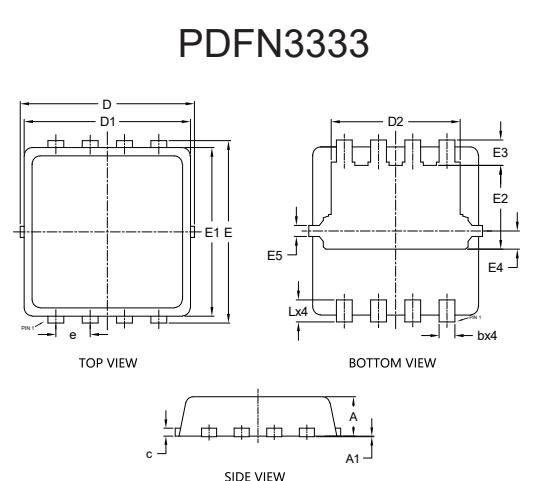
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. High Temperature Solder Exemption Applied, see EU Directive Annex 7a.
3. The value of $R_{\theta,JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.
4. Repetitive rating; pulse width limited by max. junction temperature.
5. P_D is based on max. junction temperature, using junction-case thermal resistance.
6. $T_J=25^\circ\text{C}$, $V_{DD}=40\text{V}$, $V_{GS}=10\text{V}$, $R_G=25\Omega$, $L=0.5\text{mH}$.

Internal Structure and Marking Code



4 codes in total
YY is the year
WW is the week

N-CHANNEL MOSFET



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	60			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.0	1.5	2.0	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		13.7	18	mΩ
		V _{GS} =4.5V, I _D =15A		15.7	22	
Gate Resistance	R _g	f=1 MHz, Open drain		2		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				30	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =20A			1.2	V
Reverse Recovery Time	t _{rr}	I _F =20A, dI _F /dt=100A/μs		18		ns
Reverse Recovery Charge	Q _{rr}			16		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =30V, V _{GS} =0V, f=1MHz		1850		pF
Output Capacitance	C _{oss}			100		
Reverse Transfer Capacitance	C _{rss}			90		
Total Gate Charge	Q _g	V _{DS} =30V, V _{GS} =10V, I _D =20A		38		nC
Gate-Source Charge	Q _{gs}			6.5		
Gate-Drain Charge	Q _{gd}			6.8		
Turn-On Delay Time	t _{d(on)}	V _{DD} =30V, V _{GS} =10V R _G =2.7Ω, I _D =20A		11		ns
Turn-On Rise Time	t _r			46		
Turn-Off Delay Time	t _{d(off)}			36		
Turn-Off Fall Time	t _f			8		

Curve Characteristics

Fig.1 - Typical Output Characteristics

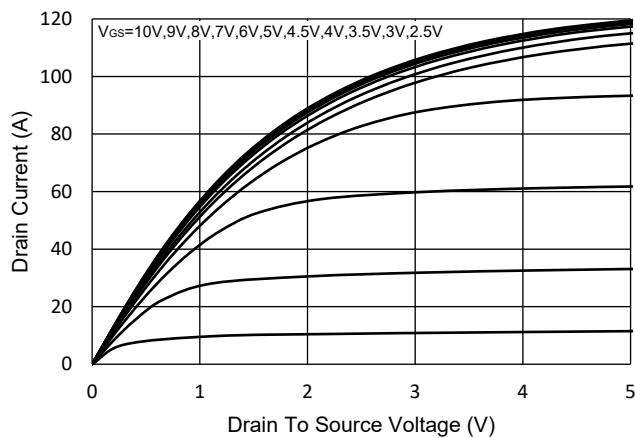


Fig.2 - Transfer Characteristics

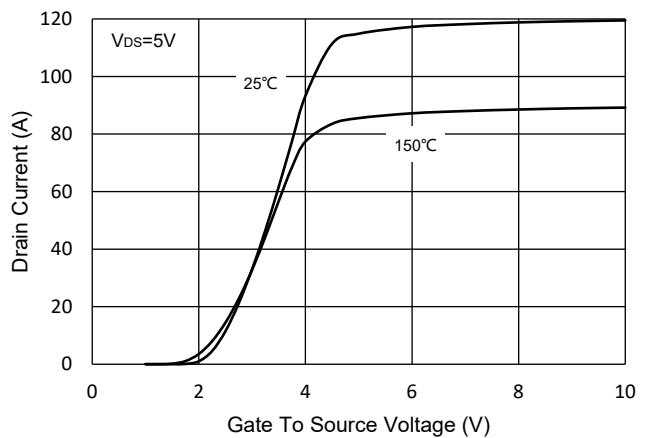


Fig.3 - $R_{DS(ON)}$ - V_{GS}

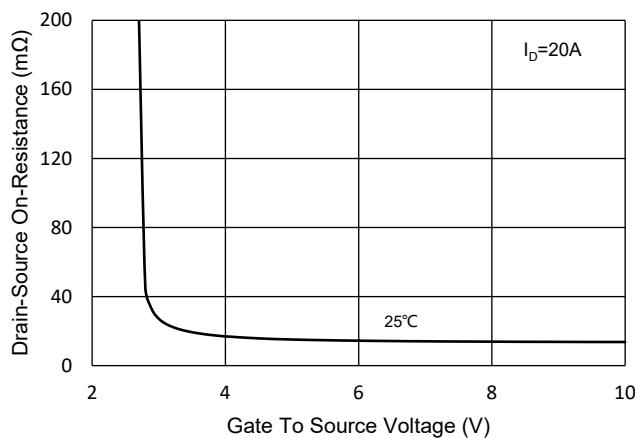


Fig.4 - $R_{DS(ON)}$ - I_D

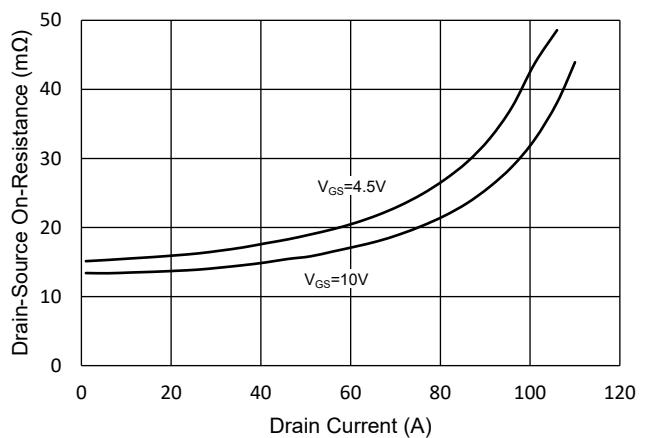


Fig.5 - Capacitance Characteristics

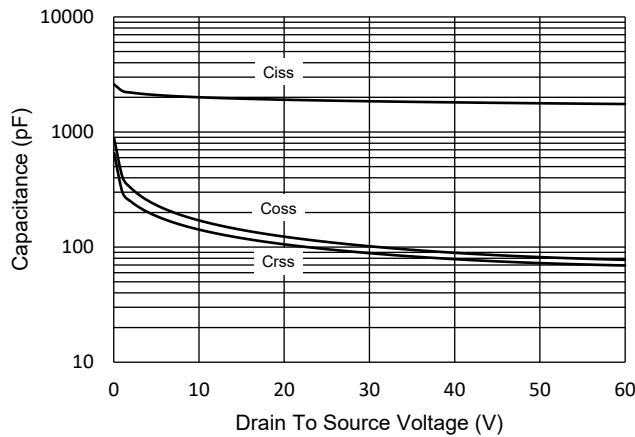
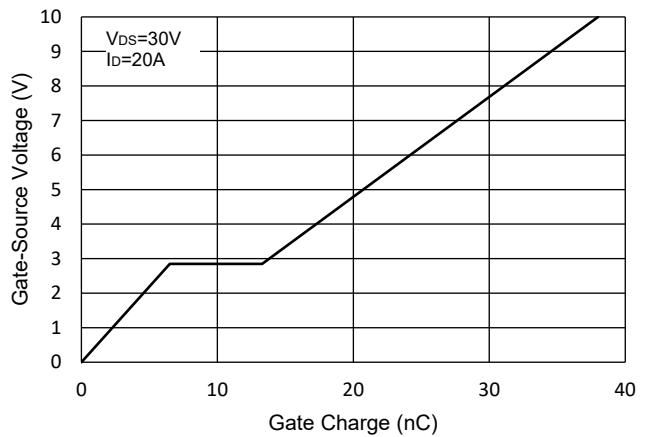


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

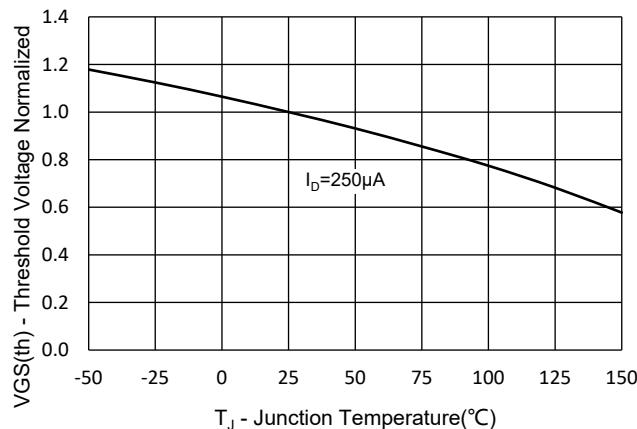


Fig.8 - Normalized On Resistance Characteristics

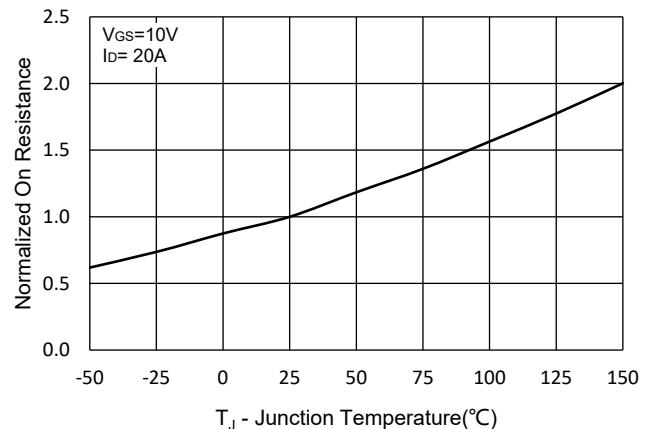


Fig.9 - I_S - V_{SD}

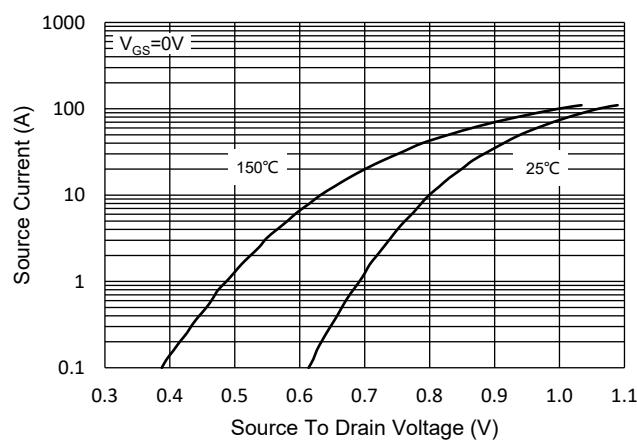


Fig.10 - Drain Current

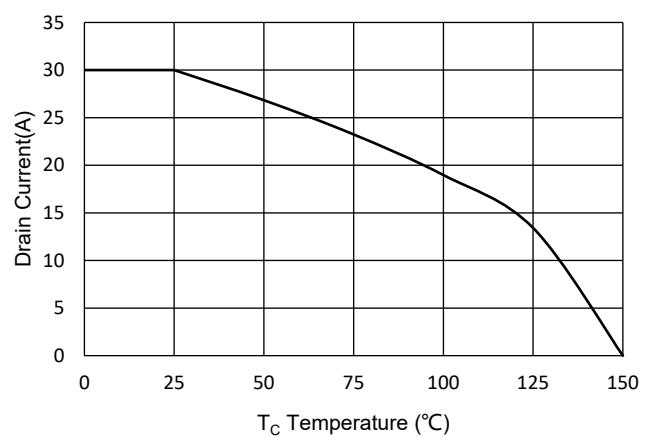
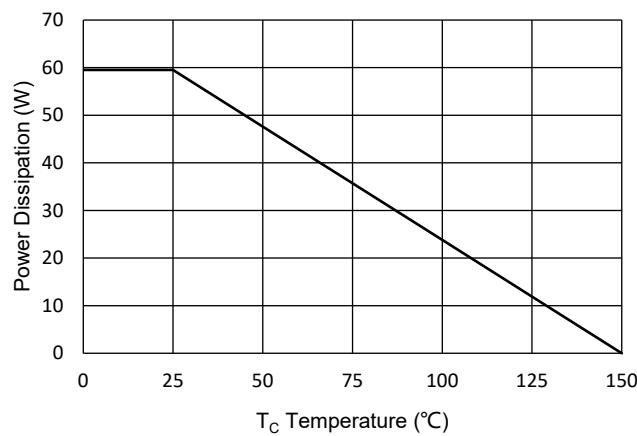


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

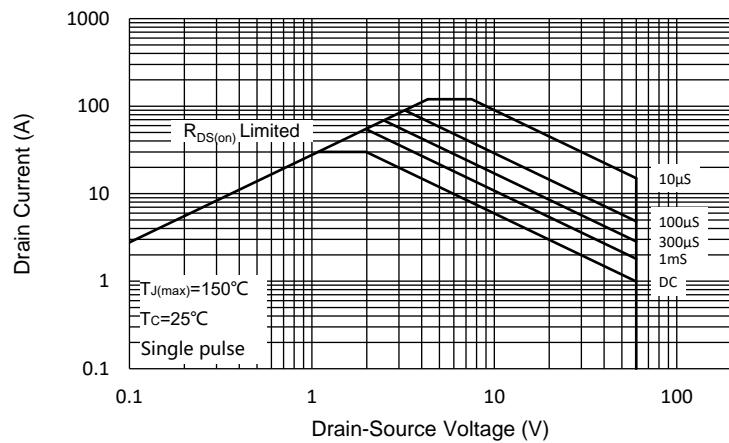
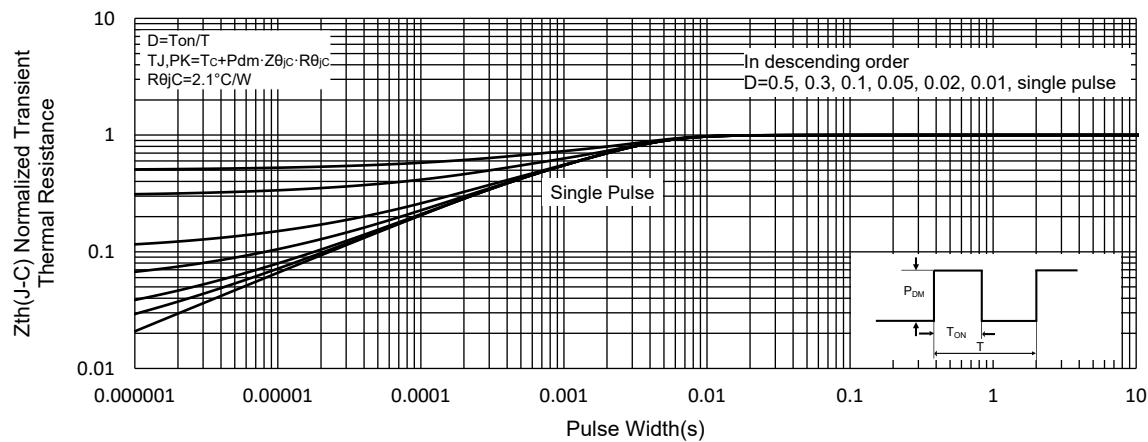


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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